

Si photodiode



S9032-02

RGB color sensor

The S9032-02 is a color sensor molded into a plastic package having a 3-channel (RGB) photodiode sensitive to the blue (λp =460 nm), green (λp =540 nm) and red (λp =620 nm) regions of the spectrum. The S9032-02 has a 3-segment (RGB) circular photosensitive area of $\phi 2$ mm.

Features

- **■** 3-channel (RGB) Si photodiode
- Surface-mount small plastic package
- **■** Spectral response range close to the human eye sensitivity
- No sensitivity in the near IR region

Applications

- Color adjustment for LED back light system for LCD
- Color adjustment for LCD projector
- Color tester
- Color detection

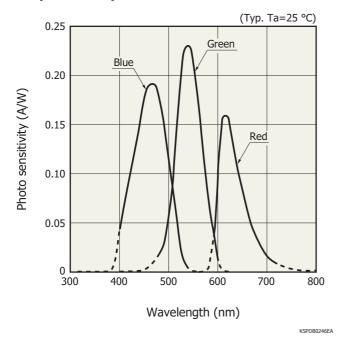
■ Absolute maximum ratings

Parameter	Symbol	Value	Unit
Reverse voltage	VR Max.	10	V
Operating temperature	Topr	-25 to +85	°C
Storage temperature	Tstg	-40 to +85	°C

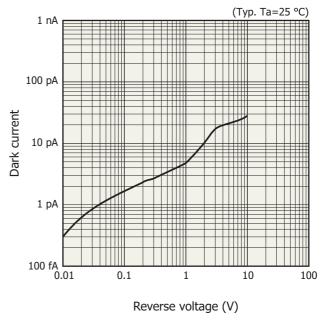
■ Electrical and optical characteristics (Ta = 25 °C, per element)

Parameter	Symbol	Condit	ion	Min.	Тур.	Max.	Unit	
		Blue		-	400 to 540	-		
Spectral response range	λ	Green		-	480 to 600	-	nm	
		Red		-	590 to 720	-		
Peak sensitivity wavelength	λр	Blue		-	460	-		
		Green		-	540	-	nm	
		Red		-	620	-		
Photo sensitivity	S	λ=λp	Blue	0.13	0.18	-	A/W	
			Green	0.18	0.23	-		
			Red	0.11	0.16	-		
Dark current	ID	V _R =1 V All elements		-	5	100	рА	
Temperature coefficient of ID	TCID			-	1.12	-	times/°C	
Rise time	tr	VR=0 V, RL=1 kΩ 10 to 90%		-	0.2	1.0	μs	
Terminal capacitance	Ct	VR=0 V f=10 kHz		-	40	80	pF	

Spectral response

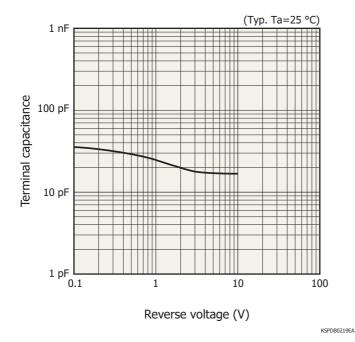


Dark current vs. reverse voltage

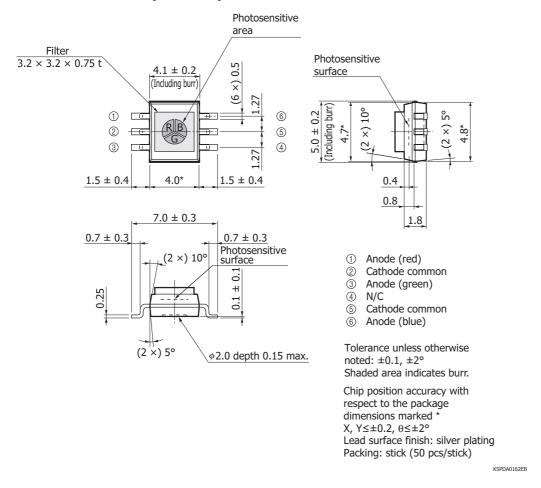


KSPDB0218EA

Terminal capacitance vs. reverse voltage



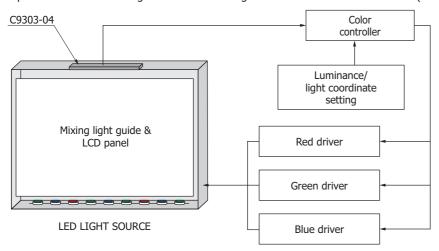
Dimensional outline (uint: mm)



Note: If excessive vibration is continuously applied to the glass filter, there is a risk that the filter may come off, so secure the glass filter with a holder.

- Application example

Optical feedback of backlight for TFT-LCD using a color sensor module C9303-04 (integrated with the S9032-02)



LED: Made by Lumileds (LUXEON), http://www.lumileds.com/

KACCC0289EA



Line-up of RGB color sensors

Type no.	Туре	Photosensitive area size (mm)	Package (mm)	ser	Peak elength nm)			Photo se	nsit	ivity	,	Photo
S9032-02	Photodiode	ф2.0	4 × 4.8 × 1.8 ^t 6-pin (filter 0.75 ^t)	B G R	460 540 620	B G R		0.18 (A/W) 0.23 (A/W) 0.16 (A/W)) [λ	=54	0 nm]	
S9702	Photodiode	1.0 × 1.0	3 × 4 × 1.3 ^t 4-pin (filter 0.75 ^t)	B G R	460 540 620	B G R		0.18 (A/W) 0.23 (A/W) 0.16 (A/W)) [λ) [λ	=46 =54	0 nm] 0 nm]	
S10917-35GT	Photodiode	1.0 × 1.0	$3 \times 1.6 \times 1.0^{t}$ COB (on-chip filter)	B G R	460 540 620	B G R		0.2 (A/W) 0.23 (A/W) 0.17 (A/W)	<u>-</u>) [λ	=54	0 nm]	
S10942-01CT	Photodiode	1.0 × 1.0	3 × 1.6 × 1.0 ^t COB (on-chip filter)		*	B G R		0.21 (A/W) 0.25 (A/W) 0.45 (A/W)) [λ	=54	0 nm]	
S9706	Digital photo IC	1.2 × 1.2	4 × 4.8 × 1.8 ^t 6-pin (filter 0.75 ^t)	B G R	465 540 615	Low	B G R	0.21 (LSB/lx) 0.45 (LSB/lx) 0.64 (LSB/lx)	High	B G R	1.9 (LSB/lx) 4.1 (LSB/lx) 5.8 (LSB/lx)	
S11012-01CR	Digital photo IC	1.2 × 1.2	$3.43 \times 3.8 \times 1.6^{t}$ COB (on-chip filter)	B G R	465 540 615	Low	B G R	0.3 (LSB/lx) 0.6 (LSB/lx) 1.4 (LSB/lx)	High	B G R	2.6 (LSB/lx) 5.3 (LSB/lx) 12.9 (LSB/lx)	

^{*} Refer to "Spectral response" of "Si photodiode S10942-01CT" datasheet.

Information described in this material is current as of October, 2011.

Product specifications are subject to change without prior notice due to improvements or other reasons. Before assembly into final products, please contact us for the delivery specification sheet to check the latest information.

Type numbers of products listed in the delivery specification sheets or supplied as samples may have a suffix "(X)" which means preliminary specifications or a suffix "(Z)" which means developmental specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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www.hamamatsu.com

 ${\it HAMAMATSU\ PHOTONICS\ K.K.,\ Solid\ State\ Division}$

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184
U.S.A.: Hamamatsu Corporation: 360 Foothill Road, P.O.Box 6910, Bridgewater, N.J. 08807-0910, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-1218
Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 8152-375-6, Fax: (49) 8152-265-8
France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10
United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welvyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-32577
North Europe: Hamamatsu Photonics Norden AB: Smidesvägen 12, SE-171 41 Solna, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01
Italy: Hamamatsu Photonics Italia S.R.L.: Strada della Moia, 1 int. 6, 20020 Arese, (Milano), Italy, Telephone: (39) 02-935-81-733, Fax: (39) 02-935-81-741